



DMG2302U

N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)

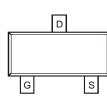




Drain

TOP VIEW

Source



TOP VIEW

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 3)	Steady State	T _A = 25°C T _A = 70°C	ID	4.2 3.4	A
Pulsed Drain Current (Note 4)			I _{DM}	27	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 3)	T _A = 25°C T _A = 70°C	Po	0.8 0.5	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$		R _{0JA}	156	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

1. No purposefully added lead.

Notes:

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

3. Device mounted on FR-4 PCB, with minimum recommended pad layout.

4. Repetitive rating, pulse width limited by junction temperature.



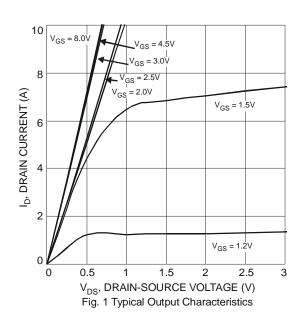
Electrical Characteristics @T_A = 25°C unless otherwise specified

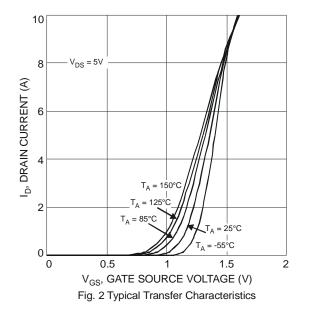
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current TJ = 25°C	I _{DSS}	-	-	1.0	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	-	-	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(th)}	0.4	-	1.0	V	$V_{DS} = V_{GS}, I_D = 50 \mu A$	
Static Drain-Source On-Resistance	Р	S (ON) -	-	90 120	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$	
	R _{DS (ON)}					V _{GS} = 2.5V, I _D = 3.1A	
Forward Transfer Admittance	Y _{fs}	-	13	-	S	$V_{DS} = 5V, I_D = 3.6A$	
Diode Forward Voltage	V _{SD}	-	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	Ciss	-	594.3	-	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss	-	64.5	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	57.7	-	pF		
Gate Resistance	Rg	-	1.5	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MH$	
Total Gate Charge	Qg	-	7.0	-	nC		
Gate-Source Charge	Q _{qs}	-	0.9	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_D = 3.6A$	
Gate-Drain Charge	Q _{gd}	-	1.4	-	nC		
Turn-On Delay Time	t _{D(on)}	-	7.4	-	ns	V _{DD} = 10V, V _{GS} = 4.5V, R _L = 2.78Ω, R _G = 1.0Ω	
Turn-On Rise Time	tr	-	9.8	-	ns		
Turn-Off Delay Time	t _{D(off)}	-	28.1	-	ns		
Turn-Off Fall Time	t _f	-	6.7	-	ns	7	

Notes:

NEW PRODUCT

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.





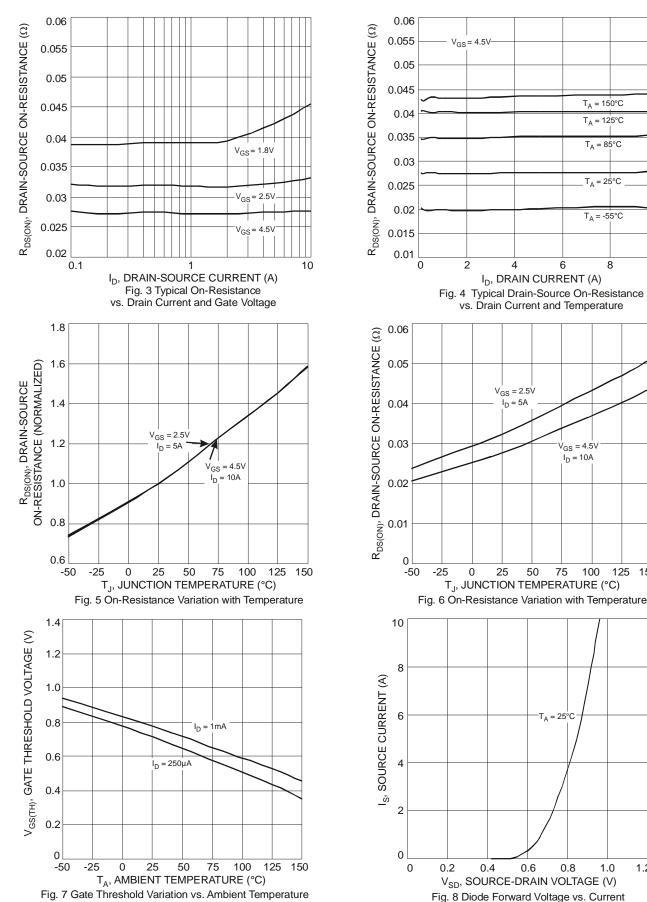


 $T_A = 85^{\circ}C$

8

10

125 150

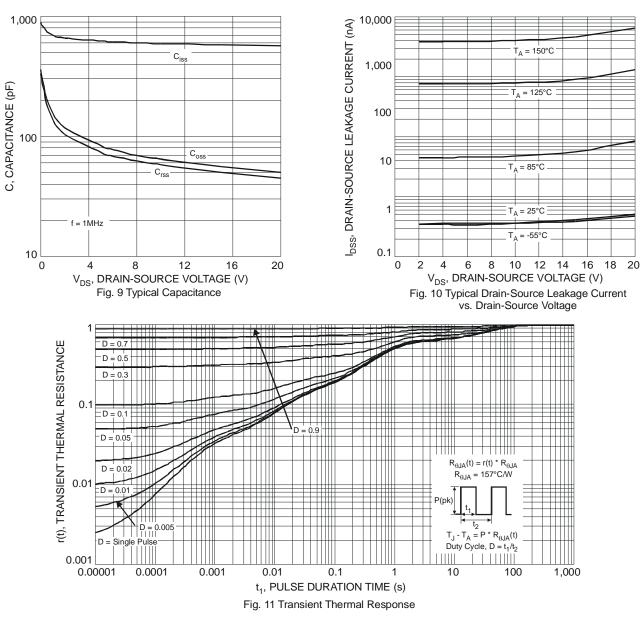


NEW PRODUCT

DMG2302U Document number: DS31838 Rev. 2 - 2 Downloaded from Elcodis.com electronic components distributor 1.2

1.0



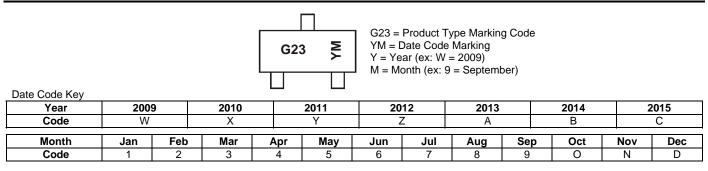


Ordering Information (Note 7)

Part Number	Case	Packaging
DMG2302U-7	SOT-23	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

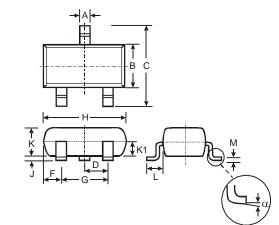
Marking Information



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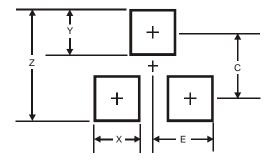
Package Outline Dimensions



SOT-23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
С	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
н	2.80	3.00	2.90	
J	0.013	0.10	0.05	
ĸ	0.903	1.10	1.00	
K1	-	-	0.400	
L	0.45	0.61	0.55	
М	0.085	0.18	0.11	
α	0°	8°	-	
All	All Dimensions in mm			

Suggested Pad Layout

NEW PRODUCT



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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